

"Minivatt"

UAF 41

Preliminary data

DIODE-PENTODE

with variable-mu

for H.F., I.F. or L.F. amplifier and detector or A.V.C.

HEATER A.C./D.C. series supply

V_f = 12,6 V
I_f = 0,100 A

CAPACITIES

pentode section

C_{a1} < 0,002 pF
C_a = 7,0 pF
C_{g1} = 4,0 pF
C_{g1f} < 0,05 pF

diode section

C_{d1} = 3,8 pF
C_{d1f} < 0,02 pF

between pentode- and diode section

C_{d1l} < 0,0015 pF
C_{d1a} < 0,15 pF

OPERATING CONDITIONS of the pentode section as H.F.- or I.F. amplifier.

V _a = V _b	100	170	200	V
R _{g2}	44	44	44	kΩ
R _k	300	300	300	Ω
V _{g1}	-1,1	-17	-2	-35 V
I _a	2,8	-	5	- mA
I _{g2}	0,9	-	1,6	- mA
S	1650	16,5	1800	1900
R _i	1	> 10	1,2	> 10 MΩ
μg ² g ₁	17	-	17	-
R _{eq}	7	-	9	- kΩ

OPERATING CONDITIONS of the pentode section as L.F. - amplifier

V _b (V)	R _a (MΩ)	R _{g2} (MΩ)	R _k (kΩ)	I _a (mA)	I _{g2} (mA)	V _o (V _{eff})	d (%)	V _o /V _i
170	0,2	0,73	2,7	0,58	0,19	6,2	1,8	78
100	0,2	0,73	2,7	0,34	0,10	4,0	1,3	73

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LIMITS of the pentode section

Vao	=	max.	550	V
Va	=	max.	250	V
Wa	=	max.	2	W
Vg2o	=	max.	550	V
Vg2 (Ia < 3 mA)	=	max.	250	V
Vg2 (Ia = 6 mA)	=	max.	150	V
Wg2	=	max.	0,3	W
Ik	=	max.	10	mA
Vgl (Igl = +0,3 pA)	=	max.	-1,3	V
Rgik	=	max.	3	M Ω
Rfk	=	max.	20	k Ω
Vfk	=	max.	150	V

LIMITS of the diode section

Vd (peak value)	=	max.	200	V
Id	=	max.	0,8	mA
Vd (Id = + 0,3 pA)	=	max.	-1,3	V
Rfk	=	max.	20	k Ω
Vfk	=	max.	150	V

Electrode arrangement, electrode connections and max. dimensions in mm.

